

isc N-Channel MOSFET Transistor

IPP65R310CFD, IIPP65R310CFD

• FEATURES

- Static drain-source on-resistance:
 R_Ds(on) ≤0.31Ω
- Enhancement mode
- · Fast Switching Speed
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

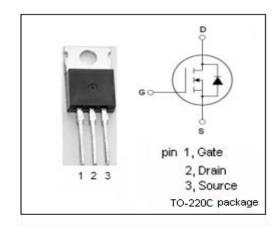
 Provide all benefits of a fast switching SJ MOSFET while offering an extremely fast and robust body diode

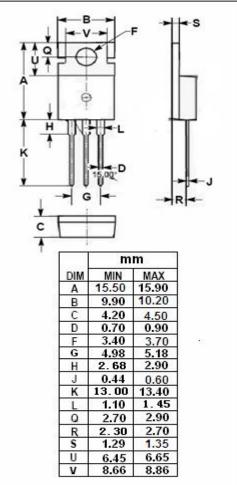
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT | |
|------------------|---|---------|------------|--|
| V _{DSS} | Drain-Source Voltage | 650 | V | |
| V _{GS} | Gate-Source Voltage | ±20 | V | |
| I _D | Drain Current-Continuous | 11.4 | А | |
| I _{DM} | Drain Current-Single Pulsed | 34.4 | А | |
| P_D | Total Dissipation @Tc=25°C | 104.2 | W | |
| Tj | Max. Operating Junction Temperature 150 | | °C | |
| T _{stg} | Storage Temperature | -55~150 | $^{\circ}$ | |

• THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|---|------------------------------------|-----|------|
| Rth(ch-c) | Channel-to-case thermal resistance | 1.2 | °C/W |
| Rth(ch-a) Channel-to-ambient thermal resistance | | 62 | °C/W |







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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | ТҮР | МАХ | UNIT |
|---------------------|--------------------------------|--|-----|-----|------|------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V; ID =1mA | 650 | | | V |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} =V _{GS} ; ID =0.4mA | 3.5 | | 4.5 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} =10V; ID=4.4A | | | 0.31 | Ω |
| I _{GSS} | Gate-Source Leakage Current | V _{GS} =20V; V _{DS} =0V | | | 0.1 | μА |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} =650V; V _{GS} = 0V | | | 1 | μА |
| V _{SD} | Diode forward voltage | I _F =6.6A; V _{GS} = 0V | | 0.9 | | V |

NOTICE:

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